

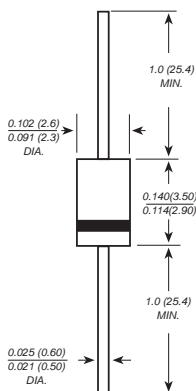


# 1S20 THRU 1SA0

## SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 100 Volts Forward Current - 1.0 Ampere

**R-1**



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length,  
5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** R-1 molded plastic body  
**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.007 ounce, 0.20 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	1S 20	1S 30	1S 40	1S 50	1S 60	1S 70	1S 80	1S 90	1S A0	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	70	80	90	100	VOLTS
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	49	56	63	70	VOLTS
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	70	80	90	100	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig.1)	$I_{AV}$	1.0									Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	40.0									Amps
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.55		0.70		0.85				Volts	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	$I_R$	0.5									mA
		10.0									
Typical junction capacitance (NOTE 1)	$C_J$	110			80						pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0									°C/W
Operating junction temperature range	$T_J$	-65 to +125			-65 to +150						°C
Storage temperature range	$T_{STG}$	-65 to +150									°C

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

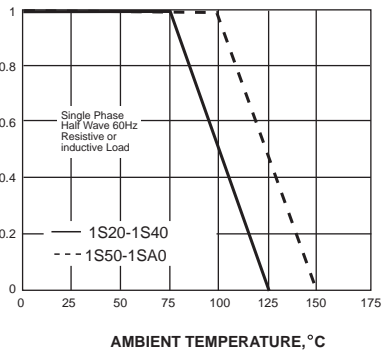
2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

**MDD ELECTRONIC**

# RATINGS AND CHARACTERISTIC CURVES 1S20 THRU 1SA0

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

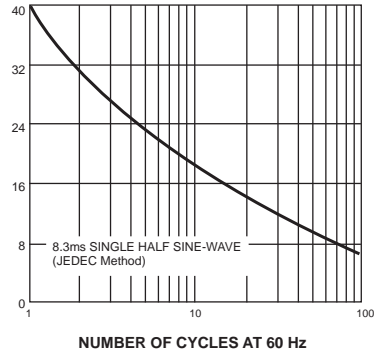
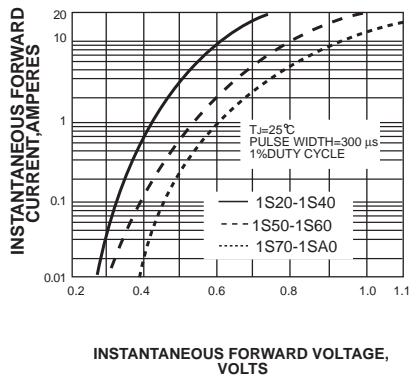


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS

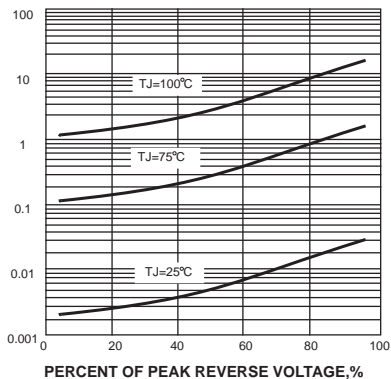
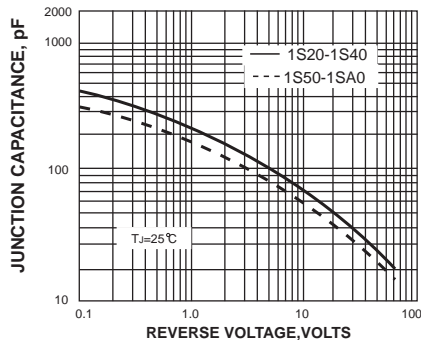


FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

